	CENTRAL INTELLIGENCE AGENCY	REPORT	
	INFORMATION REPORT	CD NO.	
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BJECT	Transistor Development at VEB Werk fuer Bauelemente der Nachrichtentechnik "Carl von Ossietzky	NO. OF PAGES	2
ACE QUIRE	(Dralowidwerk), Teltow	NO. OF ENCLS.	25X1
TE OF		SUPPLEMENT TO REPORT NO.	
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	"Carl von Ossietzky" (former Dralowid), Teltow, under Dr. Matthias Falter had not yet been completed by Audeveloped had not satisfied all requirements, particular at Interchangeability, i.e. production of sample characteristics;  b. Output; c. Temperature constancy; d. Frequency independence; e. Voltage amplification.  None of the points mentioned had been solved satistransistors had therefore not yet started. Dr. Fint that the development would reach the production so of 1955. According to plans, the production them per month. The following are the characteristics.	r the direction of gust 1954. The san alarly with respect is with exactly the san alarly with exactly the san alarly with exactly the san alarly in the first tage in the first was to be 100 to	25X1  25X1  action of expected t quarter ransistors

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25X1

25X1

25X1

Emitter veltage (Ne)
Emitter emittent (Te)
Collector veltage (Ne)
Collector current (Ne)
Voltage emplification (Vu)
Ruettel Centistanion

0.4 V finas 20 V minus 20 V 3 mā 20 18 g.

All the translators davel prior to August 1954 were germanium translators of the paint-contact type. The development planned but was not to be taken up before the development type type opening the development of the develo

Purifying of the germanium for germanium transistors is done according to the Bridgeman method. The germanium is distilled "in five zones" until it reaches a "resistance value" of 30 to 60 Ohm/cm; the purity is then five times ten power seven to one (5.10':1) (i.e. five times ten power seven germanium atoms correspond to one atom of impurity). After purifying, the germanium is mixed with "acceptame" (Akzeptoren) or "donators" (Donatoren):

- a. Borom, gallium or indium
- b. Areenic, antimony or phosphorus

In both games the mixture rate is of the order of ten power six to one (10° : 13. The final product is a germanium mencorystal mine from which dises are out for use in the transisters.

Comment: A 95mple 1/3 transistor has been assigned Sevent

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